



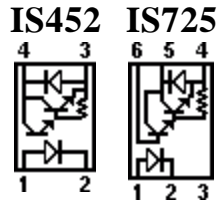
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IS452, IS725: DARLINGTON OPTOCOUPLER

Circuit



Features

- Low Input Current Requirement of 1 mA
- High Isolation Voltage
- High CTR 1000% Min

Description

The IS725 consists of a Gallium Arsenide Infrared emitting diode coupled with a silicon photodarlington which has an integral base-emitter resistor to optimise the switching speed in a dual in-line package. Surface Mount Option Available.

Applications

Telecommunications, Modem, Data Systems, Switch Mode Power Supplies, Telephone Systems.

Absolute Maximum Ratings (Ta=25°C)

Storage Temperature:	-55°C to +150°C
Operating Temperature:	-55°C to +100°C
Lead Soldering:	260°C for 10s, 1.6mm from case
Input-to-Output Isolation Test Voltage:	±4000 Vrms (Transient Overvoltage, t=10s)

Output

Collector-emitter voltage BV_{CEO} :	100V
Emitter-base voltage BV_{EBO} :	7V
Collector Dark Current:	100nA
Power Dissipation:	300/500mW
Derate Linearly:	2.00mW/°C above 25°C

Infrared Emitting Diode

Power Dissipation:	100mW
Derate Linearly:	2.00mW/°C above 25°C
Input Current (RMS):	60mA
Input Current (Peak):	±0.5A

Individual Electrical Characteristics (Ta=25°C)

C_t	Terminal Capacitance	$f=1\text{MHz}, V=0$	-50			pF
V_F	Forward Voltage	$I_F=\pm 10\text{mA}$	30	1.2	1.5	V
I_R	Reverse Current	$V_R=4\text{V}$			10	μA
OUTPUT						
BV_{CEO}	Collector-emitter Voltage	$I_C=1\text{mA}$	100			V
BV_{ECO}	Emitter-collector Voltage	$I_E=0.1\text{mA}$	7			V
I_{CEO}	Collector-emitter Dark Current	$V_{CE}=20\text{V}, I_F=0$			100	nA
COUPLED	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
I_C/I_F	DC Current Transfer Ratio	$I_F=\pm 10\text{mA}, V_{CE}=1\text{V}$	1000			%
R_{ISO}	Input-to-output Isolation Resistance	$V_{IO}=500\text{V}, RH=40\sim 60\%$	100	100		Gohm
$V_{CE(SAT)}$	Collector-emitter Saturation Voltage	$I_F=\pm 10\text{mA}, I_C=0.5\text{mA}$		0.75	1.0	V
C_{IO}	Capacitance Input to Output	$V=0, f=1\text{MHz}$			2	pF

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